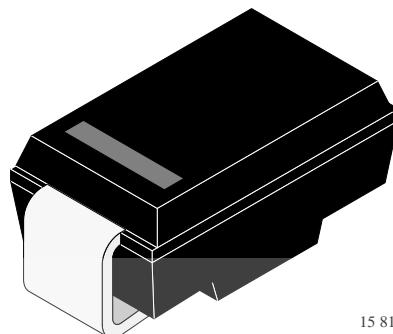


Fast Silicon Mesa SMD Rectifier

Features

- Glass passivated junction
- Low reverse current
- High reverse voltage
- Fast reverse recovery time
- Wave and reflow solderable



15 811

Applications

Freewheeling diodes in SMPS and converters
Snubber diodes

Absolute Maximum Ratings

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Value	Unit
Reverse voltage=			$V_R =$	1000	V
Repetitive peak reverse voltage			V_{RRM}		
Peak forward surge current	$t_p = 10\text{ms}$, half sinewave		I_{FSM}	30	A
Average forward current	$T_{amb} = 65^\circ\text{C}$		I_{FAV}	1.5	A
Junction and storage temperature range			$T_j = T_{stg}$	-55...+150	$^\circ\text{C}$
Pulse energy in avalanche mode, non repetitive (inductive load switch off)	$I_{(BR)R}=1\text{A}$		E_R	20	mJ

Maximum Thermal Resistance

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Symbol	Value	Unit
Junction case		R_{thJC}	25	K/W
Junction ambient	mounted on epoxy-glass hard tissue, 17mm^2 $35\mu\text{m}$ Cu	R_{thJA}	150	K/W
	mounted on epoxy-glass hard tissue, 50mm^2 $35\mu\text{m}$ Cu	R_{thJA}	125	K/W
	mounted on Al-oxid-ceramic (Al_2O_3), 50mm^2 $35\mu\text{m}$ Cu	R_{thJA}	100	K/W